One Watt Darlington Transistors

NPN Silicon

Features

• Pb-Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
	1PS6724 1PS6725	V _{CEO}	40 50	Vdc
1	1PS6724 1PS6725	V_{CBO}	50 60	Vdc
Emitter – Base Voltage		V _{EBO}	12	Vdc
Collector Current – Continuous		I _C	1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C		P_D	1.0 8.0	W mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C		P_D	2.5 20	W mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

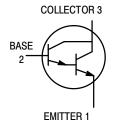
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	125	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	50	°C/W

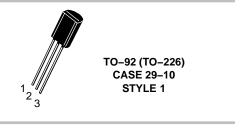
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



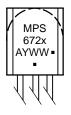
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MARKING DIAGRAM



MPS672x = Device Code x = 4 or 5

A = Assembly Location

Y = Year

WW = Work Week

= Pb-Free Package
 (Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage (Note 1) (I _C = 1.0 mAdc, I _B = 0)	MPS6724 MPS6725	V _{(BR)CES}	40 50	- -	Vdc
Collector – Base Breakdown Voltage ($I_C = 1.0 \mu Adc, I_E = 0$)	MPS6724 MPS6725	V _{(BR)CBO}	50 60	- -	Vdc
Emitter – Base Breakdown Voltage (I _E = 10 µAdc, I _C = 0)		V _{(BR)EBO}	12	-	Vdc
Collector Cutoff Current $(V_{CB} = 30 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 40 \text{ Vdc}, I_E = 0)$	MPS6724 MPS6725	Ісво	_ _	100 100	nAdc
Emitter Cutoff Current (V _{EB} = 10 Vdc, I _C = 0)		I _{EBO}	-	100	nAdc
ON CHARACTERISTICS (Note 1)					
DC Current Gain (I_C = 200 mAdc, V_{CE} = 5.0 Vdc) (I_C = 1000 mAdc, V_{CE} = 5.0 Vdc)		h _{FE}	25,000 4,000	40,000	-
Collector – Emitter Saturation Voltage (I _C = 1000 mAdc, I _B = 2.0 mAdc)		V _{CE(sat)}	-	1.5	Vdc
Base – Emitter On Voltage (I _C = 1000 mAdc, V _{CE} = 5.0 Vdc)		V _{BE(on)}	-	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product (I _C = 200 mAdc, V _{CE} = 5.0 Vdc, f = 100 MHz)		f _T	100	1000	MHz
Collector–Base Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)		C _{cb}	-	10	pF

^{1.} Pulse Test: Pulse Width \leq 300 μ s; Duty Cycle \leq 2.0%.

TYPICAL CHARACTERISTICS

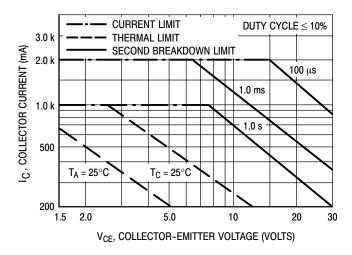


Figure 1. Active Region — Safe Operating Area

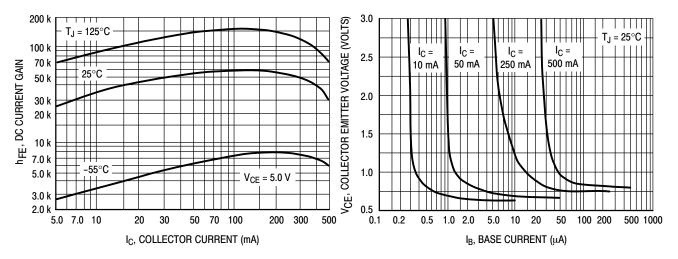


Figure 2. DC Current Gain

Figure 3. Collector Saturation Region

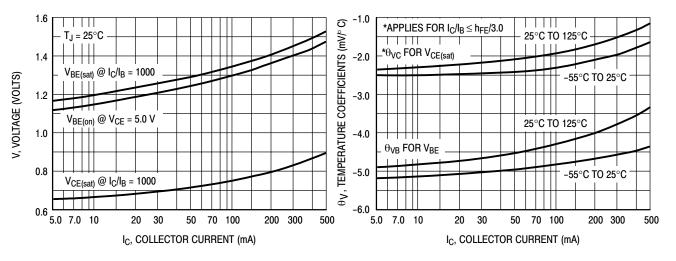


Figure 4. "ON" Voltages

Figure 5. Temperature Coefficients

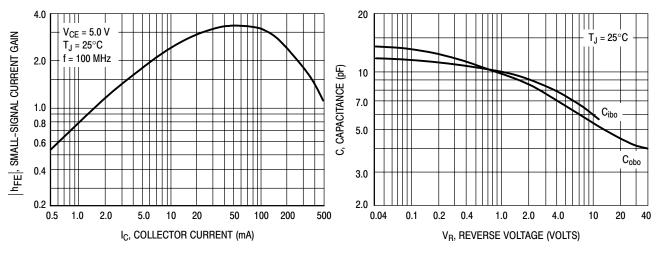


Figure 6. High Frequency Current Gain

Figure 7. Capacitance

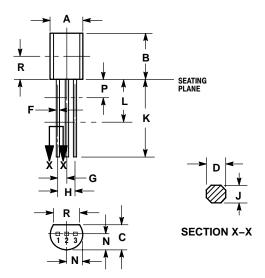
ORDERING INFORMATION

Device	Package	Shipping [†]	
MPS6724	TO-92		
MPS6724G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS6725	TO-92		
MPS6725G	TO-92 (Pb-Free)	5000 Units / Bulk	
MPS6724RLRA	TO-92		
MPS6724RLRAG	TO-92 (Pb-Free)	2000 Units / Tape & Reel	
MPS6725RLRP	TO-92	2000 Units / Tape & Ammo Box	
MPS6725RLRPG	TO-92 (Pb-Free)		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-10 ISSUE AL



NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- 4. DIMENSION F APPLIES BETWEEN P AND L
 DIMENSIONS D AND J APPLY BETWEEN L AND K
 MIMIMUM. LEAD DIMENSION IS UNCONTROLLED
 IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIM	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.44	5.21	
В	0.290	0.310	7.37	7.87	
С	0.125	0.165	3.18	4.19	
D	0.018	0.021	0.457	0.533	
F	0.016	0.019	0.407	0.482	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.018	0.024	0.46	0.61	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
P		0.100		2.54	
R	0.135		3.43		

STYLE 1: PIN 1.

IN 1. EMITTER

. BASE

3. COLLECTOR

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